

Docket No.: 21737-00013-US
(PATENT)**IN THE UNITED STATES PATENT AND TRADEMARK OFFICE**

In re Patent Application of:
Katsuki Hazama**Application No.:** 09/438,295**Confirmation No.:** 9121**Filed:** November 12, 1999**Art Unit:** 2135**For:** MULTILEVEL SEMICONDUCTOR MEMORY WRITE/
READ METHOD THERETO/THEREFROM AND
STORAGE MEDIUM STORING WRITE/READ PRO-
GRAM**Examiner:** L. Hua**CHANGE OF CORRESPONDENCE ADDRESS****Commissioner for Patents**
P.O. Box 1450
Alexandria, VA 22313-1450**Dear Sir:**

In accordance with the Manual of Patent Examining Procedures, Section 601.03, please change the mailing address for all correspondence in the above-identified patent application to:

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Please direct all further communications to the above-identified firm.

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Applicant believes no fee is due with this response. However, if a fee is due, please charge our Deposit Account No. 22-0185, under Order No. 21737-00013-US from which the undersigned is authorized to draw.

Dated: 12/01/04

Respectfully submitted,

By 
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